

Vishay High Power Products

Phase Control Thyristors (Stud Version), 200 A

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TO-209AB (TO-93)

FEATURES

- · Center amplifying gate
- International standard case TO-209AB (TO-93)



ROHS

- Hermetic metal case with ceramic insulator (Also available with glass-metal seal up to 1200 V)
- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Lead (Pb)-free
- Designed and qualified for industrial level

PRODUCT SUMMARY	Y
I _{T(AV)}	200 A

TYPICAL APPLICATIONS

- · DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		200	А		
$I_{T(AV)}$	T _C	85	°C		
I _{T(RMS)}		314	А		
I _{TSM}	50 Hz	5000	۸		
	60 Hz	5230	Α		
101	50 Hz	125	kA ² s		
l ² t	60 Hz	114	KA-S		
V _{DRM} /V _{RRM}		400 to 2000	V		
t _q	Typical	100	μs		
T _J		- 40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA			
	04	400	500				
	08	800	900				
ST180S	12	1200	1300	30			
	16	1600	1700				
	20	2000	2100				

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ST180SPbF Series

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ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL		TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	180° condu	ction half sine v	waye.	200	Α
at case temperature	'I(AV)	180° conduction, half sine wave		85	°C	
Maximum RMS on-state current	I _{T(RMS)}	DC at 76 °C	case temperati	ure	314	
		t = 10 ms	No voltage		5000	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		5230	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		4200	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	4400	
Maximum I ² t for fusing		t = 10 ms	No voltage reapplied	initial T _J = T _J maximum	125	
	l ² t	t = 8.3 ms			114	
		t = 10 ms	100 % V _{RRM}		88	
		t = 8.3 ms	reapplied		81	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	ms, no voltage	reapplied	1250	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$, $T_J = T_J$ maximum	1.08	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(A)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum			1.18	m 0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			1.14	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 570 \text{ A}, T_J = 125 ^{\circ}\text{C}, t_p = 10 \text{ ms sine pulse}$		1.75	V	
Maximum holding current	I _H			600	mA	
Maximum (typical) latching current	ΙL	$T_J = T_J$ maximum, anode supply 12 V resistive load 1000 (300)			1000 (300)] "''A

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V_{DRM}	1000	A/µs	
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0		
Typical turn-off time	tq	$I_{TM}=300~A,~T_J=T_J~maximum,~dl/dt=20~A/\mu s, \\ V_R=50~V,~dV/dt=20~V/\mu s,~gate~0~V~100~\Omega,~t_p=500~\mu s$	100	μs	

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA		



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TRIGGERING						
PARAMETER	SYMBOL			VALUES		
PARAMETER	STINIBUL	'	EST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	, t _p ≤ 5 ms	1	0	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	, f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	, $t_p \le 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	$$ $T_J = T_J$ maximum, $t_0 \le 5$ ms		0	V	
Maximum peak negative gate voltage	- V _{GM}			5.0		V
	I _{GT}	T _J = - 40 °C	Maximum required gate trigger/	180	-	mA
DC gate current required to trigger		T _J = 25 °C		90	150	
		T _J = 125 °C current/voltage are the lowest		40	-	
		T _J = - 40 °C	value which will trigger all units	2.9	-	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T _J = 125 °C			-	
DC gate current not to trigger	I _{GD}	T - T movimum	Maximum gate current/voltage not to trigger is the maximum	1	10	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		- 40 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 40 to 150		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.105	IZ AAZ	
Maximum thermal resistance, case to heatsink	R _{thC-hs}	Mounting surface, smooth, flat and greased	0.04	K/W	
Mounting torque, ± 10 %		Non-lubricated threads	31 (275)	N·m	
		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheeet TO-209AB (TO-93)		O-93)	

△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.015	0.012				
120°	0.019	0.020				
90°	0.025	0.027	$T_J = T_J \text{ maximum}$	K/W		
60°	0.036	0.037				
30°	0.060	0.060				

Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJC} \, \text{when devices operate at different conduction angles than DC} \,$

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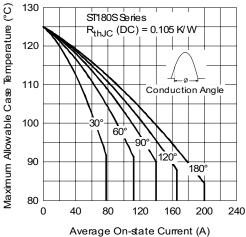


Fig. 1 - Current Ratings Characteristics

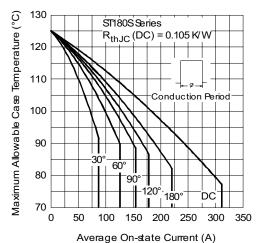


Fig. 2 - Current Ratings Characteristics

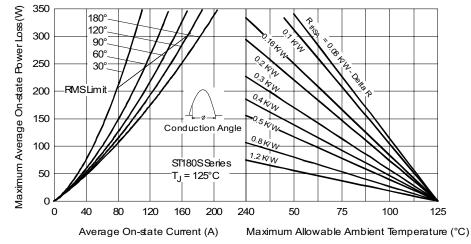


Fig. 3 - On-State Power Loss Characteristics

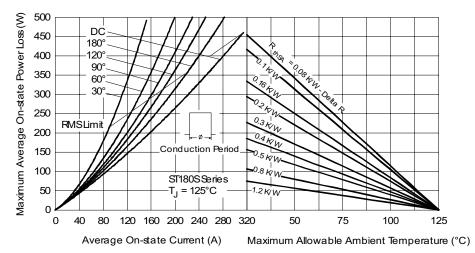


Fig. 4 - On-State Power Loss Characteristics



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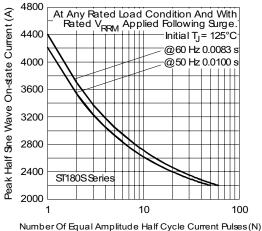


Fig. 5 - Maximum Non-Repetitive Surge Current

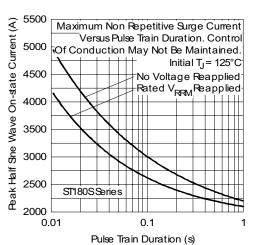


Fig. 6 - Maximum Non-Repetitive Surge Current

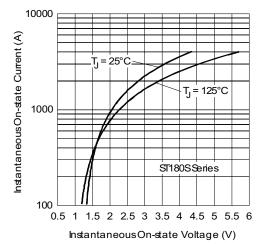


Fig. 7 - On-State Voltage Drop Characteristics

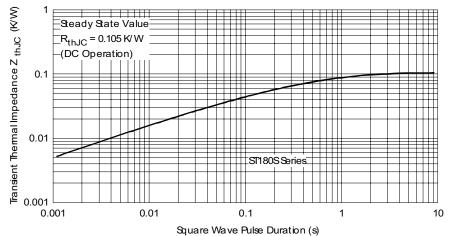
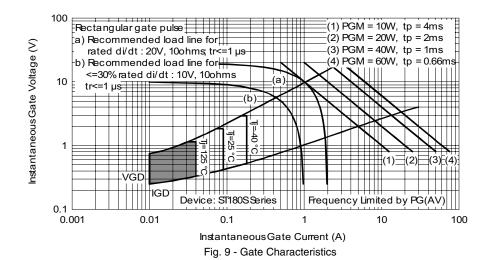


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

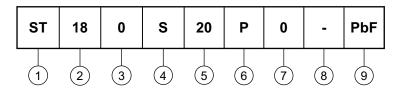
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Device code

ORDERING INFORMATION TABLE



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- S = Compression bonding stud
- Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6 P = Stud base 3/4"-16UNF2A threads
- 7 0 = Eyelet terminals (gate and auxiliary cathode leads)
 - 1 = Fast-on terminals (gate and auxiliary cathode leads)
- 8 V = Glass-metal seal (only up to 1200 V)

None = Ceramic housing (over 1200 V)

9 - Lead (Pb)-free

Note: For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95082		

www.vishay.com

For technical questions, contact: ind-modules@vishay.com

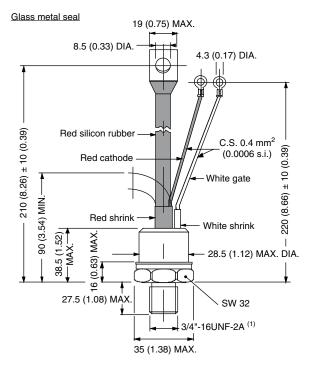
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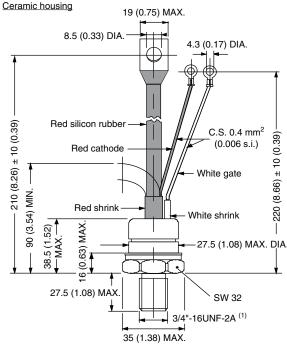


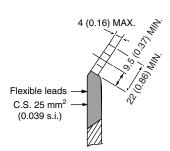
Vishay Semiconductors

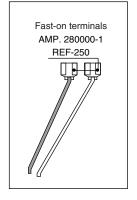
TO-209AB (TO-93)

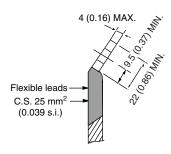
DIMENSIONS in millimeters (inches)











Note

(1) For metric device: M16 x 1.5 - length 21 (0.83) maximum



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